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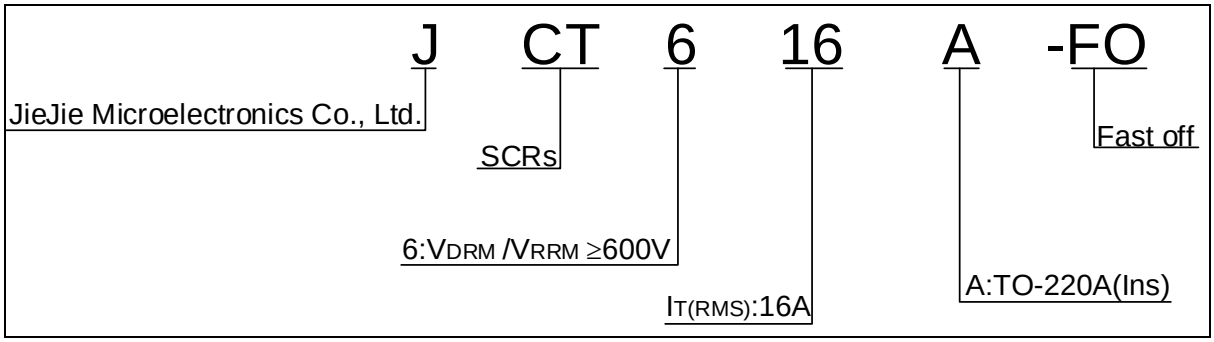
Average gate power dissipation	$P_{G(AV)}$	1	W
Peak gate power	P_{GM}	5	W
Peak pulse voltage (T_j=25 ; non-repetitive,off-state;FIG.7)	Vpp	0.7	kV

ELECTRICAL CHARACTERISTICS (T_j=25 unless otherwise specified)

Symbol	Test Condition	Value			Unit
		MIN.	TYP.	MAX.	
I_{GT}	V_D=12V R_L=33Ω	3	-	6	mA
V_{GT}		-	-	1.3	V
V_{GD}	V_D=V_{DRM}				

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ORDERING INFORMATION



MARKING

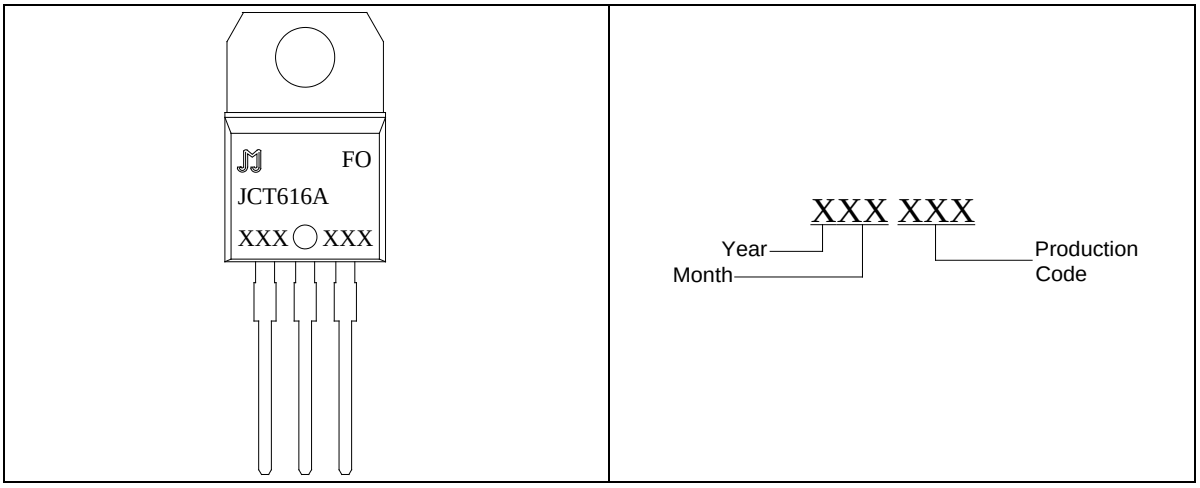
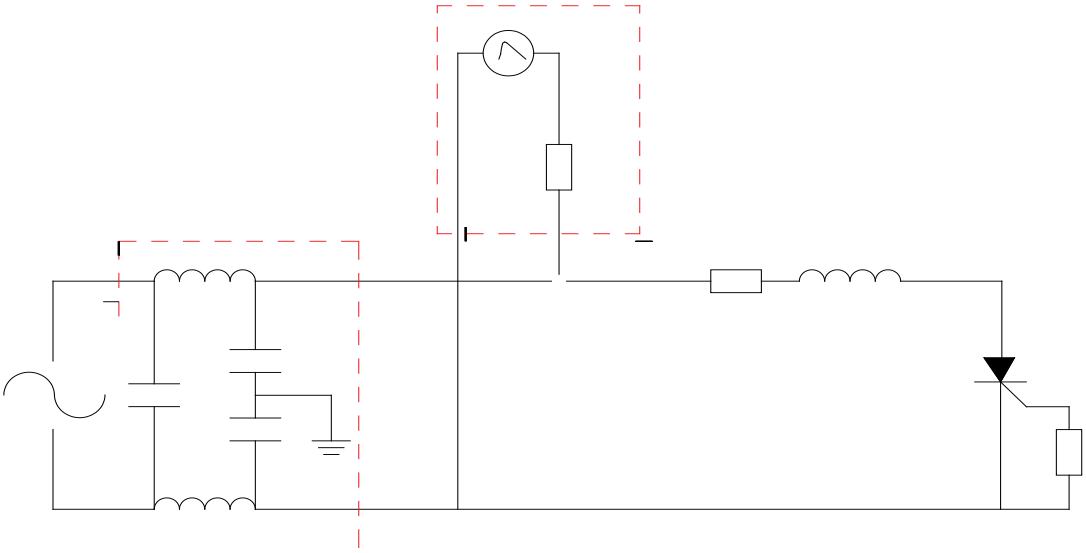


FIG.1

FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



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